

Fault pruning:

Robust training of neural networks with memristive weights

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 - Synaptic plasticity: ability to increase or decrease synaptic weights by means of changes in conductance.
 - Main features: neuron-synapse structure, in-memory computation, learning capabilities



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 - (a) Resistive Random Access Memory (RRAM),
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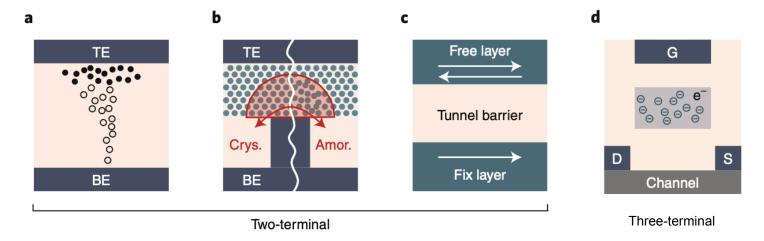


Image source:

Zhang, Wenqiang, et al. "Neuro-inspired computing chips." *Nature electronics* 3.7 (2020): 371-382.



- Key metrics for performance evaluation:
 - Computing density
 - Energy-efficiency
 - Computing accuracy: influenced by non-idealities of devices
 - Learning capabilities: off-chip, on-chip, hybrid



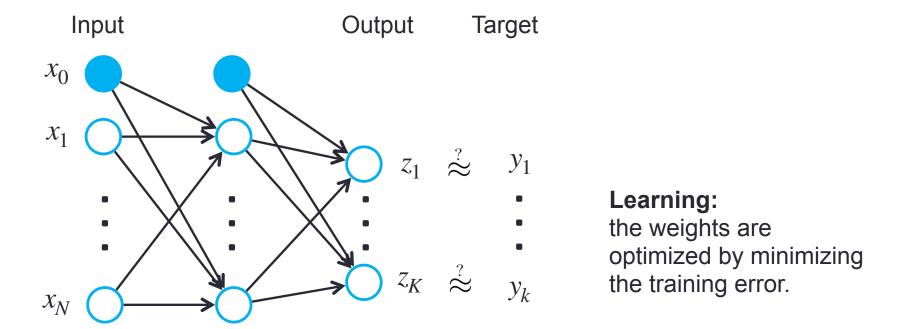
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Our focus:

- RRAM devices ("memristors")
- Improving energy-efficiency
- Learning "in-the-loop":
 - robust training of neural networks with memristive weights
 - detection of faulty memristors
 - improving computing accuracy



Introduction: Neural networks

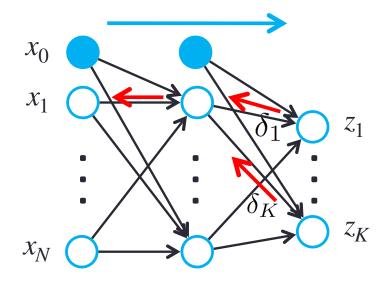


e.g.,
$$E = \frac{1}{2} \sum_{k=1}^{K} e_k^2 = \frac{1}{2} \sum_{k=1}^{K} (z_k - y_k)^2$$



Introduction: Neural networks

- For learning, the gradient of the error function is needed.
 - Forward: Calculate activations and outputs of all neurons.
 - Backward: Calculate errors and propagate them back





Introduction: Memristors

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Challenges:

- Fabrication, operational constraints
- Limited endurance of the devices
- Yield and repeatability issues



Memristive neural network training

Faulty behavior of memristors

- Stuck memristors
- Faulty updates
 - Concordant switching faults
 - Discordant switching faults

This significantly reduces network performance.



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Our approach:

- Analyze impact of faulty memristor behavior on neural network training
- Strategy: Use Fault pruning.
 Detection of faults during training and pruning of connections on the fly.



Memristive weights

■ Mapping resistance $R_i \in [R_{\min}, R_{\max}]$ to weight $w_i \in [w_{\min}, w_{\max}]$:

$$w_i = \alpha \left(\frac{1}{R_i} - \frac{1}{R_C}\right)$$



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Weight and resistance updates:

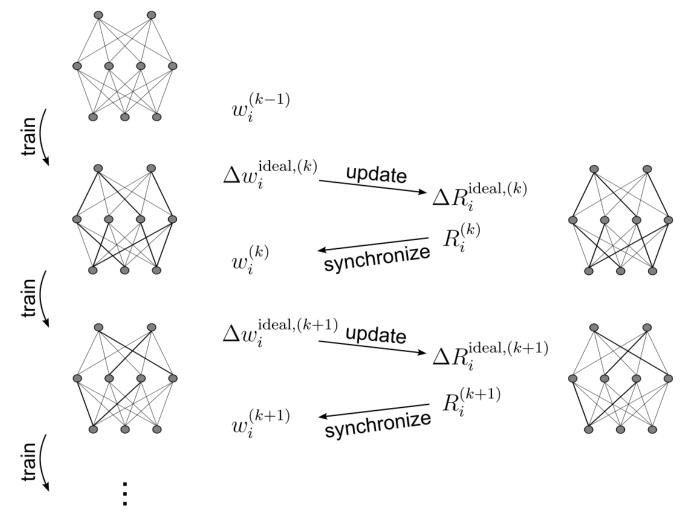
$$\Delta w_i = w_i^{(k)} - w_i^{(k-1)}$$
$$\Delta R_i = R_i^{(k)} - R_i^{(k-1)}$$



In-the-loop training

High-precision network

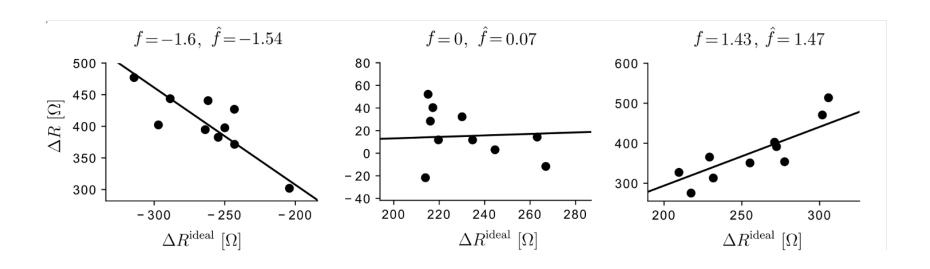
Memristive network





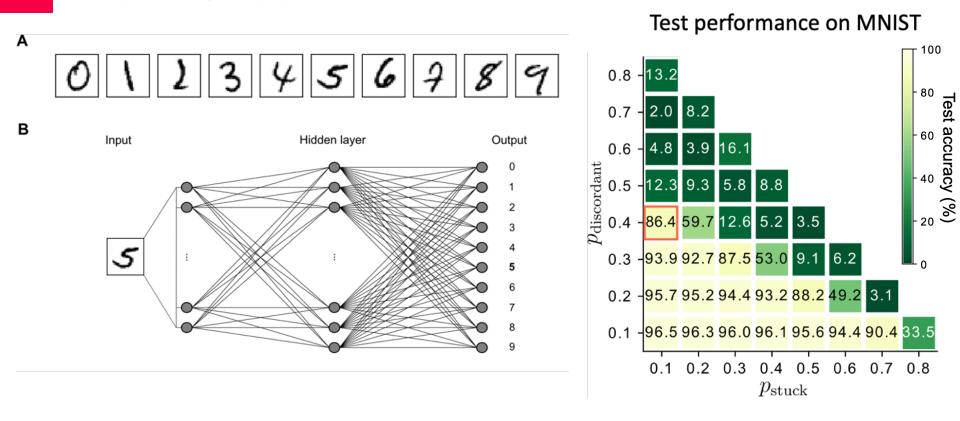
Model of imperfect memristor

- Memristor faults modeled by fault factor f_i
 - Modulates memristance change: $\Delta R_i^{(k)} = f_i \cdot \Delta R_i^{\text{ideal, }(k)} + \eta_i^{(k)}$
 - Stuck memristors: $f_i = 0$
 - Concordant changes: $f_i > 0$
 - Discordant changes: $f_i < 0$
 - Switching and readout noise $\eta_i^{(k)}$ added.





The MNIST task



Discordant memristive changes are detrimental.

Neural networks can be pruned significantly and achieve little loss in accuracy, hence we asked if one can prune faulty memristive connections.



Fault pruning algorithm

Estimate fault factor over a window of previous updates:

$$\hat{f}_i = \frac{\sum_l \Delta R_i^{\text{ideal},(l)} \Delta R_i^{(l)}}{\sum_l \left(\Delta R_i^{\text{ideal},(l)}\right)^2}$$



Fault pruning algorithm

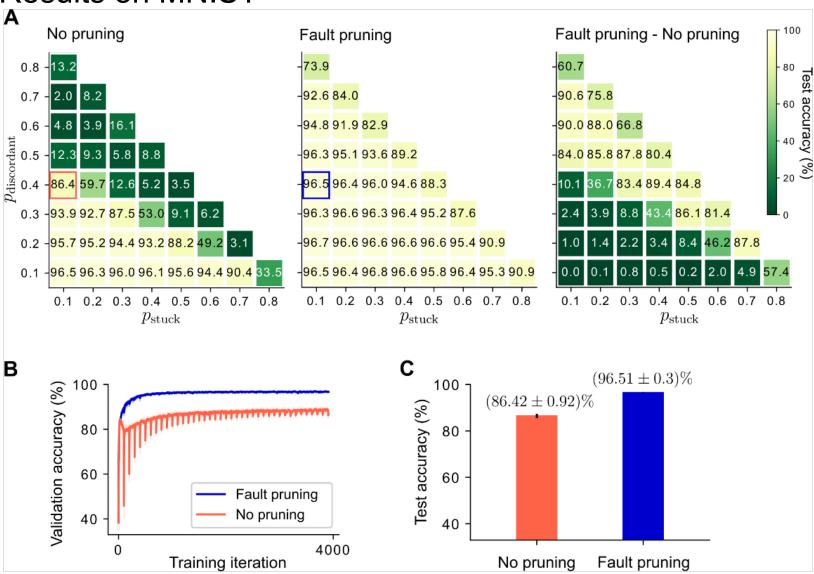
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- Remove detected unreliable memristors from the network if $\hat{f}_i < \theta$, and we set $\theta = 0.1$
- Two variants of the algorithm
 - Variant 1: Prune faulty weights (set to zero)
 - Variant 2: Don't update faulty weights (keep last weight)

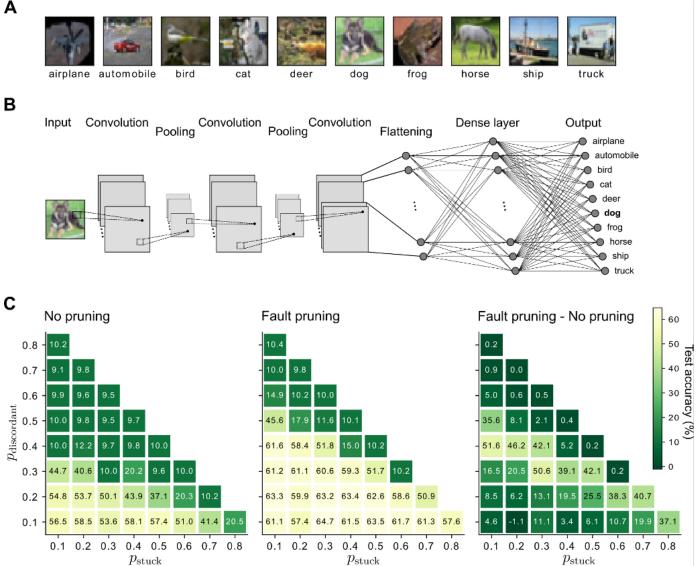


Results on MNIST



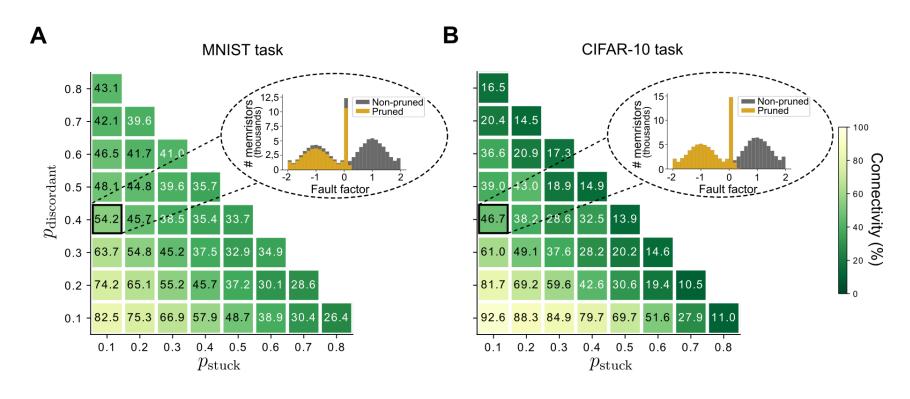


Results on CIFAR-10





Connectivity in the network after pruning





Summary and Conclusion

- Fault pruning managed to preserve very good performance
- Estimation of faults on the fly, and acting accordingly
- General approach, independent of the network structure and trained tasks
- A simple linear regression to estimate faults
 - Can be substituted by more advanced approaches

Future work:

- Test the algorithm in a real-world scenario
- Handling memristors with discordant faults by adapting the requested update





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Estimation of the fault factors \hat{f}_i

$$\Delta R_i = \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal}} + \epsilon$$

Estimated from N=10 data points $(\Delta R_i^{\mathsf{ideal},(l)}, \Delta R_i^{(l)}), \ l \in \{k-N+1, k-N+2, ..., k-1, k\}$

The least-squares estimator of \hat{f}_i minimises the error

$$\mathscr{L}(\hat{f}_i) := \sum_{l} \left(\Delta R_i^{(l)} - \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal},(l)} \right)^2,$$

$$\frac{\partial \mathcal{L}}{\partial \hat{f}_i} = 2\sum_{l} \left(\Delta R_i^{(l)} - \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal},(l)} \right) \left(-\Delta R_i^{\mathsf{ideal},(l)} \right) \stackrel{!}{=} 0$$

$$\hat{f}_i \sum_{l} \left(\Delta R_i^{\mathsf{ideal},(l)} \right)^2 = \sum_{l} \Delta R_i^{(l)} \Delta R_i^{\mathsf{ideal},(l)}$$

$$\hat{f}_i = \frac{\sum_l \Delta R_i^{(l)} \Delta R_i^{\mathsf{Ideal},(l)}}{\sum_l \left(\Delta R_i^{\mathsf{ideal},(l)}\right)^2}$$